CMPT491E

ENHANCED SPECIFICATION SURFACE MOUNT NPN SILICON TRANSISTOR





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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPT491E type is an Enhanced version of the industry standard 491 NPN silicon transistor. This device is manufactured by the epitaxial planar process and epoxy molded in an SOT-23 surface mount package. The CMPT491E features Low VCE(SAT), high hFE, and has been designed for high current general purpose amplifier applications.

MARKING CODE: C49

COMPLEMENTARY TYPE: CMPT591E

FEATURED ENHANCED SPECIFICATIONS:

- ♦ VCE(SAT) @ 1.0A = 0.4V MAX (from 0.5V MAX)
- ♦ hFE @ 500mA = 200 MIN (from 100 MIN)

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	l _C	1.0	Α
Continuous Base Current	ΙB	200	mA
Peak Collector Current	I _{CM}	2.0	Α
Power Dissipation	P_{D}	350	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	ΘιΔ	357	°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _{CBO}	V _{CB} =60V		100	nA
I _{EBO}	V _{EB} =4.0V		100	nA
BV _{CBO}	I _C =100μA	80		V
BV _{CEO}	I _C =10mA	60		V
BV _{EBO}	I _E =100μA	5.0		V
♦ V _{CE(SAT)}	I _C =500mA, I _B =50mA		0.20	V
♦ V _{CE(SAT)}	I _C =1.0A, I _B =100mA		0.40	V
V _{BE(SAT)}	I _C =1.0A, I _B =100mA		1.1	V
V _{BE} (ON)	V _{CE} =5.0V, I _C =1.0A		1.0	V
♦ h _{FE}	V _{CE} =5.0V, I _C =1.0mA	200		
♦ h _{FE}	V _{CE} =5.0V, I _C =500mA	200	600	
h_{FE}	V _{CE} =5.0V, I _C =1.0A	50		
h_{FE}	V _{CE} =5.0V, I _C =2.0A	15		
f _T	V_{CE} =10V, I_{C} =50mA, f=100MHz	150		MHz
C _{ob}	V_{CB} =10V, I_E =0, f=1.0MHz		10	pF

◆ Enhanced specification

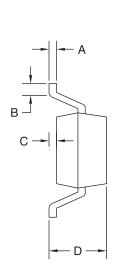
R4 (27-January 2010)

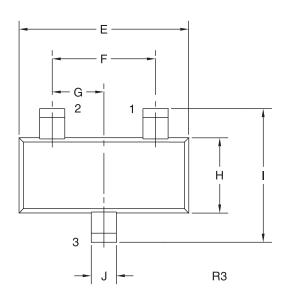
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SOT-23 CASE - MECHANICAL OUTLINE





LEAD CODE:

- 1) Base 2) Emitter 3) Collector

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DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.003	0.007	0.08	0.18			
В	0.006	-	0.15	-			
С	-	0.005	-	0.13			
D	0.035	0.043	0.89	1.09			
E	0.110	0.120	2.80	3.05			
F	0.075		1.90				
G	0.037		0.95				
Н	0.047	0.055	1.19	1.40			
ĺ	0.083	0.098	2.10	2.49			
J	0.014	0.020	0.35	0.50			

SOT-23 (REV: R3)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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